# NSN 5961-00-050-3463

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Inclosure Material:

Metal

**Overall Length:** 

0.672 inches

# **Overall Diameter:**

0.505 inches

# **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

### Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

#### **Mounting Method:**

Threaded stud

# Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

0.430 inches

# Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

25.0 breakdown voltage, collector-to-base, emitter open

#### **Current Rating Per Characteristic:**

1.00 amperes collector current, dc

#### **Power Rating Per Characteristic:**

30.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius ambient air

#### **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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# Demilitarization:

No

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